

## PSBD2ED40V2H

## Schottky Barrier Diode

#### Feature

- Small mold type. (DFN1608-2L)
- Low IR
- High reliability.

#### **Applications**

Low current rectification

#### **Mechanical Characteristics**

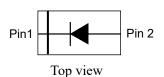
- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:260°C
- > Device meets MSL 1 requirements
- Pure tin plating: 7 ~ 17 um
- ➢ Pin flatness∶≤3mil

## Electrical characteristics per line@25°C

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VF	-	0.53	0.56	V	I <sub>F</sub> =1A
Forward voltage	VF	-	0.60	0.65	V	I⊧=1.5A
Reverse current	IR	-	-	50	uA	V <sub>R</sub> =40V
Junction Capacitance	Cj	-	150	-	pF	V <sub>R</sub> =0V,f=1MHz
Reverse Recovery Time	trr		25		ns	IF=0.5A, IR=1.0A, Irr=0.25A

#### Absolute maximum rating@25℃

Parameter	Symbol	limits	Unit
Reverse voltage (DC)	V <sub>RM</sub>	40	V
Average rectified forward current	lo	2	A
Typical Thermal Resistance Junction to Ambient	R <sub>thja</sub>	80	°C/W
Peak Forward Surge Current 8.3ms Single Half Sine Wave Superimposed on Rated Load	Ігѕм	12	A
Repetitive Peak Forward Current (Pulse Wave=10ms, Duty Cycle = 25%)	IFRM	5	A
Operating and Storage Temperature Range	Tj ,Tstg	-55 to 125	°C



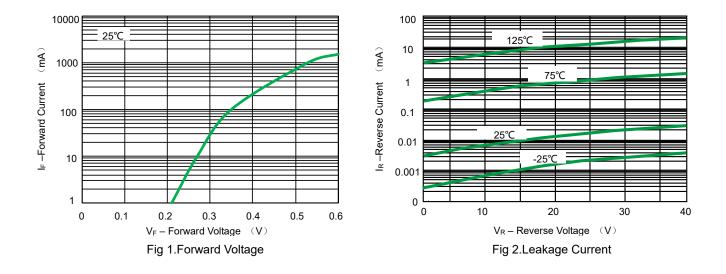
#### Construction

Silicon epitaxial planar

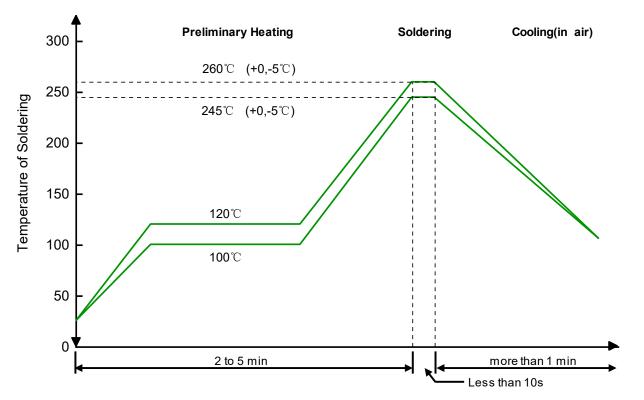
## Schottky Barrier Diode

#### PSBD2ED40V2H

### **Typical Characteristics**



#### **Solder Reflow Recommendation**

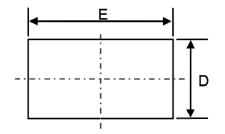


Remark: Pb free for 260°C; Pb for 245°C.

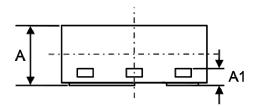
## Schottky Barrier Diode

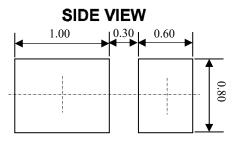
## PSBD2ED40V2H

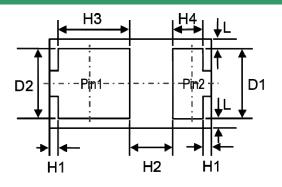




### **TOP VIEW**







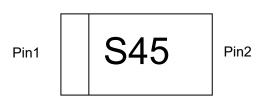
### **BOTTOM VIEW**

Dim	Millimeters			
	MIN	МАХ		
А	0.53	0.65		
A1	0.13 Ref.			
E	1.55	1.65		
D	0.75	0.85		
D1	0.60	0.80		
D2	0.60	0.80		
L	0.025	0.075		
H1	0.025	0.075		
H2	0.38 Ref.			
H3	0.76 Ref.			
H4	0.36 Ref.			

Notes: This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.

Ordering information		
Device	Package	Shipping
PSBD2ED40V2H	DFN1608-2L(Pb-free)	5000 / Tape & Reel

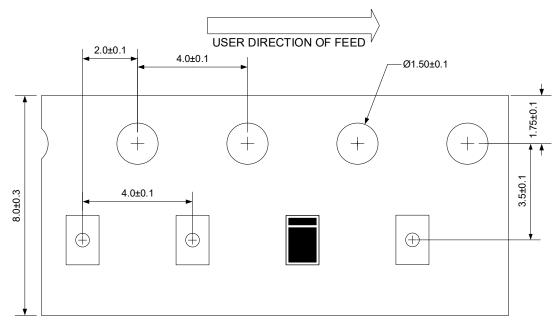
## Marking



# Schottky Barrier Diode

## PSBD2ED40V2H

## Load with information



Unit:mm

#### **IMPORTANT NOTICE**

*Q* and **Prisemi** are registered trademarks of **Prisemi Electronics Co., Ltd** (Prisemi), Prisemi reserves the right to make changes without further notice to any products herein. Prisemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Prisemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in Prisemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Prisemi does not convey any license under its patent rights nor the rights of others. The products listed in this document are designed to be used with ordinary electronic equipment or devices, Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

Website: http://www.prisemi.com For additional information, please contact your local Sales Representative. ©Copyright 2009, Prisemi Electronics Prisemi<sup>®</sup> is a registered trademark of Prisemi Electronics. All rights are reserved.